# **IGBT - Field Stop**

600 V, 40 A

# FGH40N60SF

### Description

Using novel field stop IGBT technology, ON Semiconductor's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.

#### Features

- High Current Capability
- Low Saturation Voltage:  $V_{CE(sat)} = 2.3 \text{ V} @ I_C = 40 \text{ A}$
- High Input Impedance
- Fast Switching:  $E_{OFF} = 8 \mu J/A$
- This Device is Pb-Free and is RoHS Compliant

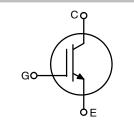
#### Applications

• Solar Inverter, UPS, Welder, PFC



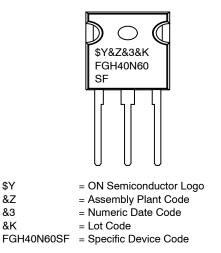
# **ON Semiconductor®**

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#### MARKING DIAGRAM



## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

Descrip	Symbol	Ratings	Unit	
Collector to Emitter Voltage		V <sub>CES</sub>	600	V
Gate to Emitter Voltage		V <sub>GES</sub>	±20	V
Transient Gate-to-Emitter Voltage		1 [	±30	
Collector Current	$T_{C} = 25^{\circ}C$	Ι <sub>C</sub>	80	А
Collector Current	T <sub>C</sub> = 100°C	1 [	40	А
Pulsed Collector Current	urrent $T_{\rm C} = 25^{\circ}{\rm C}$		120	А
aximum Power Dissipation $T_{\rm C} = 25^{\circ}{\rm C}$		PD	290	W
Maximum Power Dissipation T <sub>C</sub> = 100°C		7 F	116	W
Operating Junction Temperature		TJ	–55 to +150	°C
Storage Temperature Range		T <sub>stg</sub>	-55 to +150	°C
Maximum Lead Temp. for Soldering Purp	ΤL	300	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Repetitive rating: Pulse width limited by max. junction temperature.

#### **THERMAL CHARACTERISTICS**

Parameter	Symbol	Тур	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$ (IGBT)	-	0.43	°C/W
Thermal Resistance, Junction to Ambient	$R_{\thetaJA}$	-	40	°C/W

#### PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH40N60SFTU	FGH40N60SF	TO-247	Tube	N/A	N/A	30

## **ELECTRICAL CHARACTERISTICS OF THE IGBT** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
OFF CHARACTERISTICS								
Collector to Emitter Breakdown Voltage	BV <sub>CES</sub>	$V_{GE}$ = 0 V, I <sub>C</sub> = 250 $\mu$ A	600	-	-	V		
Temperature Coefficient of Breakdown Voltage	$\Delta BV_{CES}/\Delta T_{J}$	$V_{GE}$ = 0 V, I <sub>C</sub> = 250 µA	-	0.6	-	V/°C		
Collector Cut-Off Current	I <sub>CES</sub>	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA		
G-E Leakage Current	I <sub>GES</sub>	$V_{GE} = V_{GES}, V_{CE} = 0 V$	_	-	±400	nA		

#### **ON CHARACTERISTICs**

G-E Threshold Voltage	V <sub>GE(th)</sub>	$I_C$ = 250 $\mu$ A, $V_{CE}$ = $V_{GE}$	4.0	5.0	6.5	V
Collector to Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V	-	2.3	2.9	V
		$I_C$ = 40 A, $V_{GE}$ = 15 V, $T_C$ = 125°C	-	2.5	-	V

<b>ELECTRICAL CHARACTERISTICS OF THE IGB1</b>	$(T_{\rm C} = 25^{\circ}{\rm C} \text{ unless otherwise noted})$ (continued)
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Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS		-		•		
Input Capacitance	C <sub>ies</sub>	$V_{CE}$ = 30 V, $V_{GE}$ = 0 V, f = 1 MHz	-	2110	-	pF
Output Capacitance	C <sub>oes</sub>		-	200	-	pF
Reverse Transfer Capacitance	C <sub>res</sub>	-	-	60	-	pF
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{CC} = 400 \text{ V}, \text{ I}_{C} = 40 \text{ A},$	-	25	-	ns
Rise Time	t <sub>r</sub>	$R_G = 10 \Omega$ , $V_{GE} = 15 V$ , Inductive Load, $T_C = 25$ °C	_	42	-	ns
Turn-Off Delay Time	t <sub>d(off)</sub>		-	115	-	ns
Fall Time	t <sub>f</sub>		-	27	54	ns
Turn-On Switching Loss	E <sub>on</sub>		-	1.13	-	mJ
Turn-Off Switching Loss	E <sub>off</sub>		-	0.31	-	mJ
Total Switching Loss	E <sub>ts</sub>			1.44	-	mJ
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{CC} = 400 \text{ V}, \text{ I}_{C} = 40 \text{ A},$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ Inductive Load, $T_{C} = 125^{\circ}\text{C}$	-	24	-	ns
Rise Time	t <sub>r</sub>		-	43	-	ns
Turn-Off Delay Time	t <sub>d(off)</sub>		-	120	-	ns
Fall Time	t <sub>f</sub>		-	30	-	ns
Turn-On Switching Loss	E <sub>on</sub>	-	-	1.14	-	mJ
Turn-Off Switching Loss	E <sub>off</sub>		-	0.48	-	mJ
Total Switching Loss	E <sub>ts</sub>		_	1.62	-	mJ
Total Gate Charge	Qg	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V	_	120	-	nC
Gate to Emitter Charge	Q <sub>ge</sub>		_	14	-	nC
Gate to Collector Charge	Q <sub>gc</sub>		_	58	_	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **TYPICAL PERFORMANCE CHARACTERISTICS**

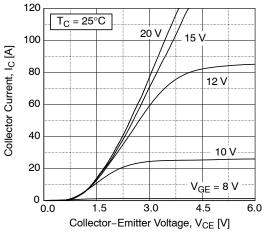


Figure 1. Typical Output Characteristics

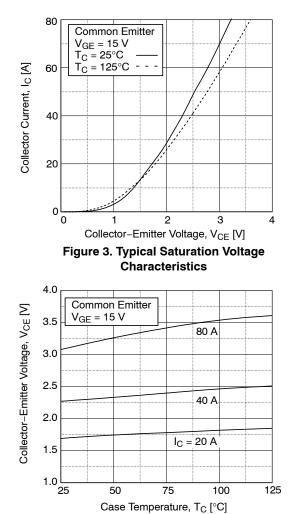


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

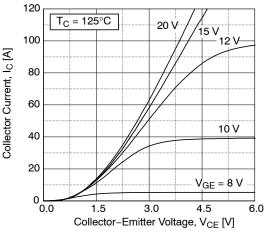
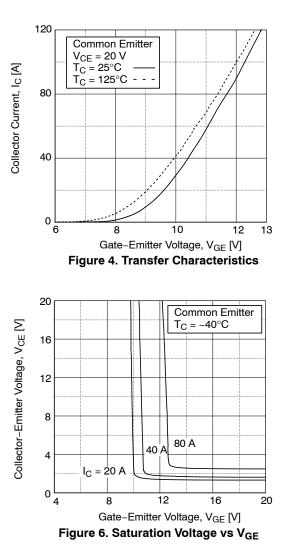


Figure 2. Typical Output Characteristics



## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

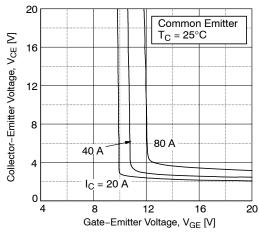


Figure 7. Saturation Voltage vs. V<sub>GE</sub>

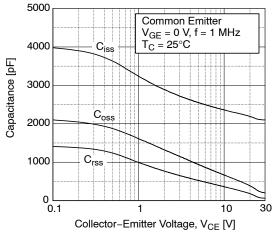
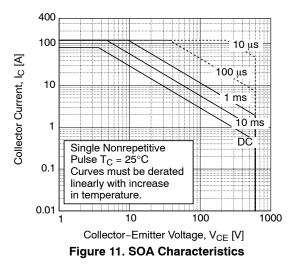
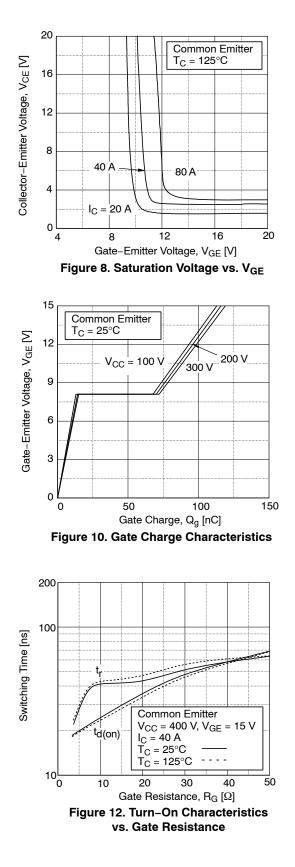
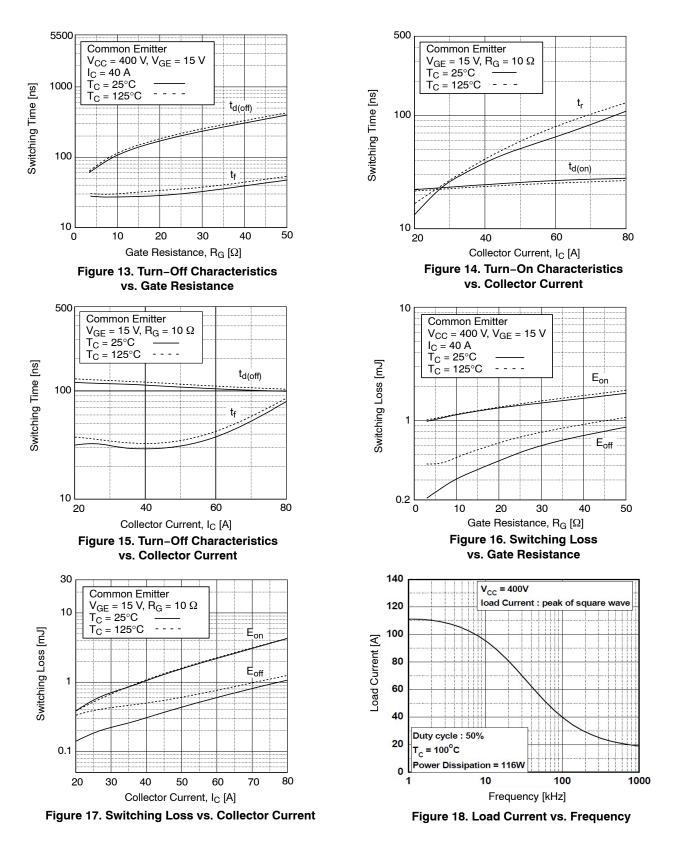


Figure 9. Capacitance Characteristics





## TYPICAL PERFORMANCE CHARACTERISTICS (continued)



## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

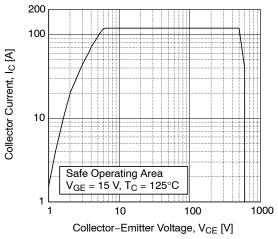
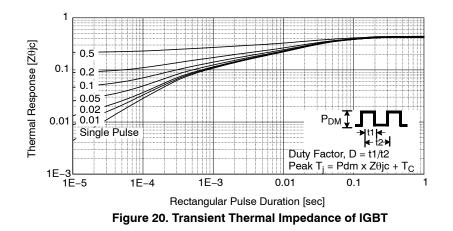


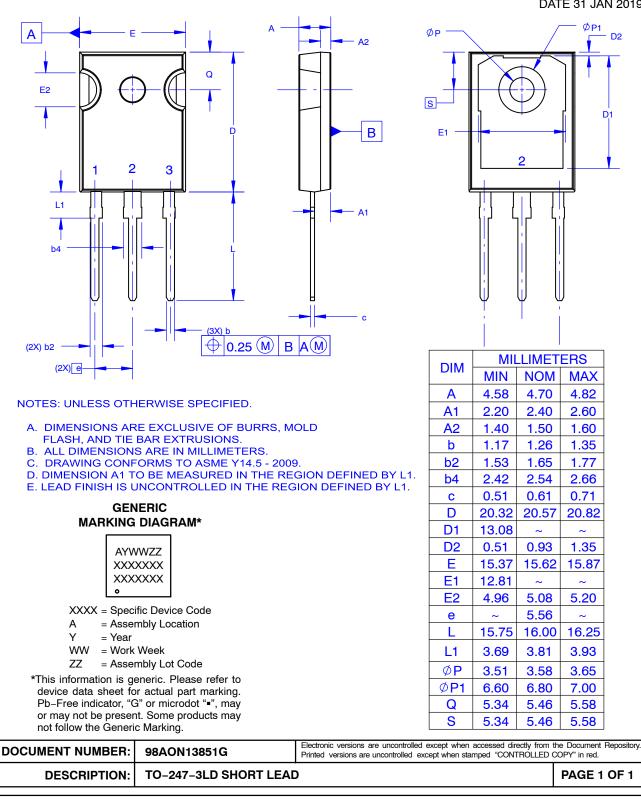
Figure 19. Turn-Off Switching SOA Characteristics





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DATE 31 JAN 2019



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